

# Standard Rectifier

Single Diode

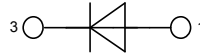
$$V_{RRM} = 1800 \text{ V}$$

$$I_{FAV} = 30 \text{ A}$$

$$V_F = 1.25 \text{ V}$$

Part number

**DMA 30 E 1800 HA**



Backside: anode

**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

**Applications:**

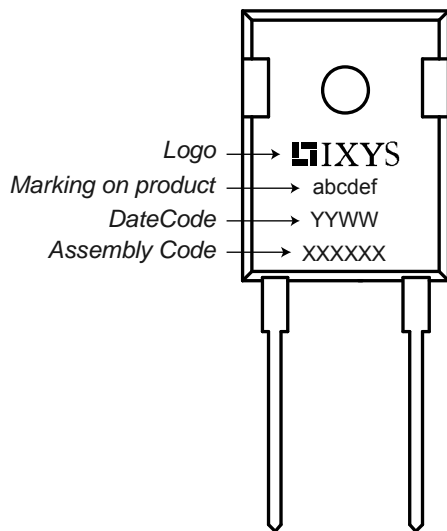
- Diode for main rectification
- For single and three phase bridge configurations

**Package:**

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Symbol	Definition	Conditions	Ratings			Unit	
			min.	typ.	max.		
$V_{RRM}$	max. repetitive reverse voltage				1800	V	
$I_R$	reverse current	$V_R = 1800 \text{ V}$			40	$\mu\text{A}$	
		$V_R = 1800 \text{ V}$			1.5	mA	
$V_F$	forward voltage	$I_F = 30 \text{ A}$			1.27	V	
		$I_F = 60 \text{ A}$			1.50	V	
		$I_F = 30 \text{ A}$	$T_{VJ} = 150^\circ\text{C}$			1.25	V
		$I_F = 60 \text{ A}$	$T_{VJ} = 150^\circ\text{C}$			1.57	V
$I_{FAV}$	average forward current	rectangular d = 0.5	$T_C = 140^\circ\text{C}$		30	A	
$V_{F0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 175^\circ\text{C}$		0.88	V	
$r_F$	slope resistance				12.1	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.70	K/W	
$T_{VJ}$	virtual junction temperature		-55		175	$^\circ\text{C}$	
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		210	W	
$I_{FSM}$	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$		370	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 \text{ V}$		400	A	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ\text{C}$		315	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 \text{ V}$		340	A	
$I^2t$	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$		685	A <sup>2</sup> s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 \text{ V}$		665	A <sup>2</sup> s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ\text{C}$		495	A <sup>2</sup> s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 \text{ V}$		480	A <sup>2</sup> s	
$C_J$	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		10	pF	

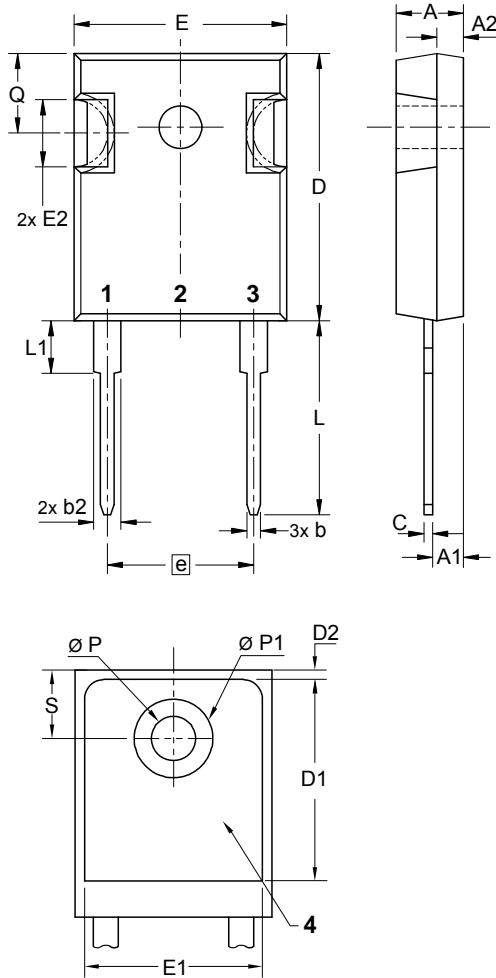
Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
$I_{RMS}$	RMS current	per pin			70	A
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g
$M_D$	mounting torque		0.8		1.2	Nm
$F_C$	mounting force with clip		20		120	N

**Product Marking**

**Part number**

D = Diode  
 M = Standard Rectifier  
 A = (up to 1800 V)  
 30 = Current Rating [A]  
 E = Single Diode  
 1800 = Reverse Voltage [V]  
 HA = TO-247AD (2)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DMA 30 E 1800 HA	DMA30E1800HA	Tube	30	455156

### Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.430 BSC		10.92 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39